

Features

- Frequency Range: DC~12GHz
- Isolation: >45dB@12GHz
- Insertion loss: 1.2dB@12GHz
- Control Voltage: 0/+5V
- Die Size: 1.4mm×1.25mm×0.1mm

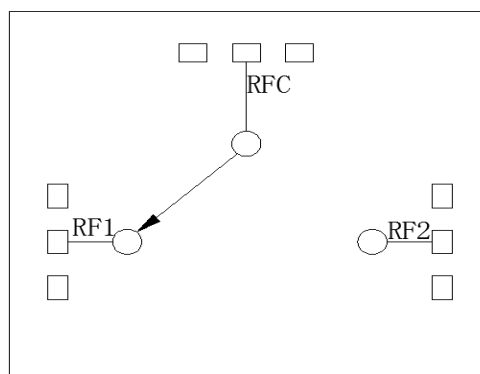
Typical Applications

- Radar and ECM
- RF/ Microwave radio
- Military and Space
- Test and Measurement
- Fiber Optics

General Description

XT3202 is a general purpose broadband high isolation reflective GaAs pHEMT SPDT switch in bare die. The switch offers over 45 dB isolation and less than 1.2 dB insertion loss over operation frequency. Its fast switching and compact size make this SPDT ideal for a lot of critical applications. The switch operates using complementary positive control voltage logic lines of 0/+5V.

Functional Diagram



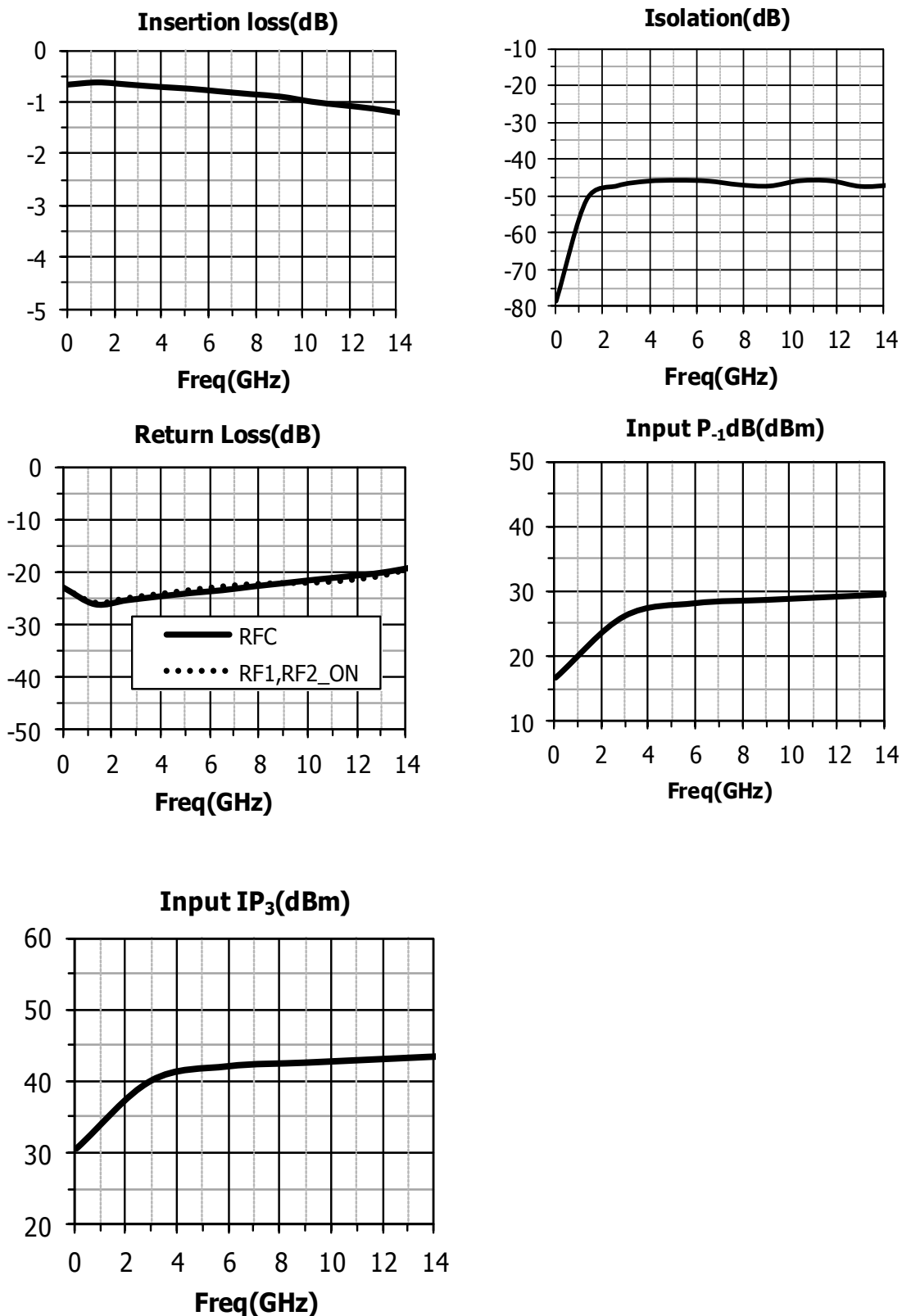
Electrical Performance ($T_A=+25^{\circ}\text{C}$, $V_D=-5\text{V}$, Control Voltage=0/+5V, $Z_0=50\Omega$)

Parameter	Freq.	Min.	Typ.	Max.	Units
Insertion Loss	DC~12GHz	—	-1.2	—	dB
Isolation	DC~12GHz	—	-48	—	dB
Return Loss(RFC)	DC~12GHz	—	-20	—	dB
Return Loss(RF1,RF2(ON))	DC~12GHz	—	-20	—	dB
Input $P_{1\text{dB}}$	DC~12GHz	—	25	—	dBm
Input IP_3	DC~12GHz	—	42	—	dBm
Switching Speed	DC~12GHz	—	18	—	ns

Absolute Maximum Ratings

Input power	30dBm	Control Voltage Range	0~5.5V
Channel Temperature	150°C	Storage Temperature	-65°C~+150°C
Operating Temperature	-55°C~+85°C	ESD Sensitivity (HBM)	Class 1A

Typical Performance Curve



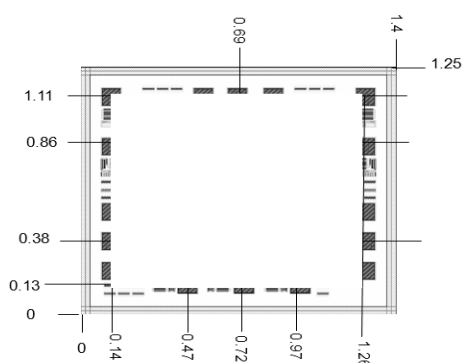
Control Voltages

State	Bias Condition
Low	0~0.5V
High	4.5~5.5V

Bias Voltage & Current

V_D	I_D
-5V	1mA

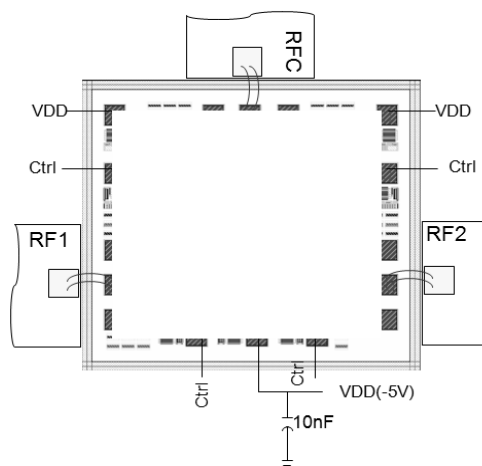
Die Outline (all dimensions in mm)



Truth Table

Control Input	Signal Path State	
Control	RFC-RF1	RFC-RF2
Low	ON	OFF
High	OFF	ON

Assembly Diagram



Attention:

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.